

FX50KMJ-2

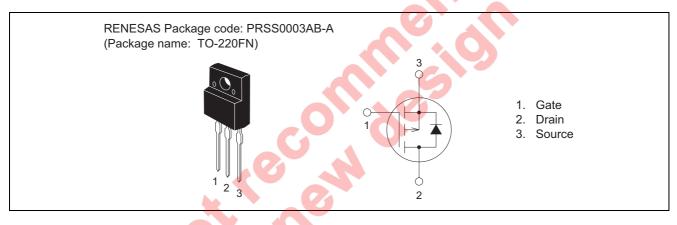
High-Speed Switching Use Pch Power MOS FET

> REJ03G1452-0200 (Previous: MEJ02G0284-0101) Rev.2.00 Aug 07, 2006

Features

- Drive voltage : 4 V
- V_{DSS} : -100 V
- $r_{\text{DS(ON)}(\text{max})}$: 50 m Ω
- I_D: -50 A
- Integrated Fast Recovery Diode (TYP.): 100 ns
- Viso : 2000 V

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

				$(\mathrm{Tc} = 25^{\circ}\mathrm{C})$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	-100	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	ID	-50	A	
Drain current (Pulsed)	I _{DM}	-200	A	
Avalanche drain current (Pulsed)	I _{DA}	-50	A	L = 30 μH
Source current	Is	-50	A	
Source current (Pulsed)	I _{SM}	-200	A	
Maximum power dissipation	PD	35	W	
Channel temperature	Tch	- 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Isolation voltage	Viso	2000	V	AC for 1 minute,
-				Terminal to case
Mass		2.0	g	Typical value



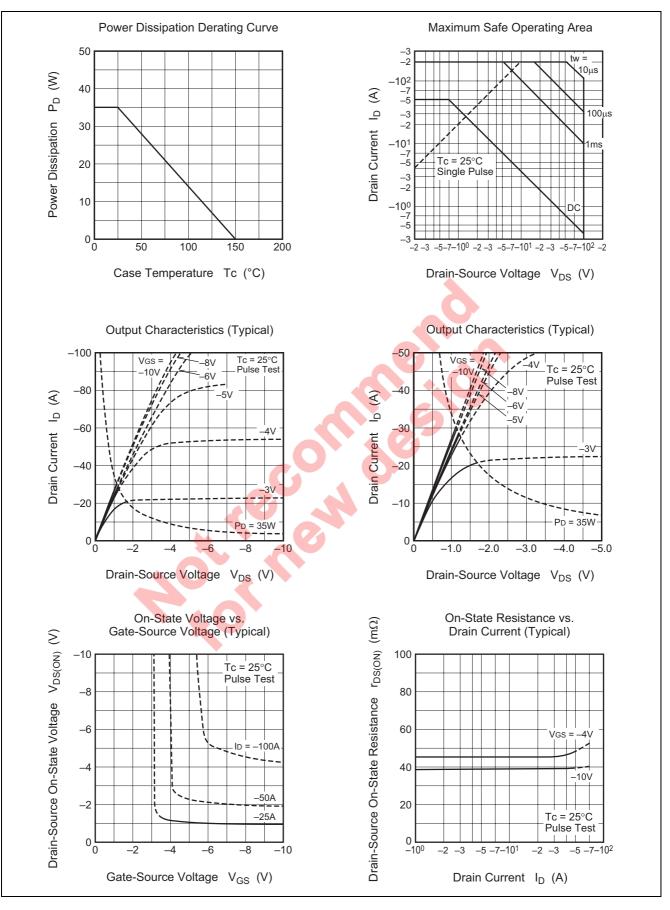
Electrical Characteristics

(Tch	=	25°	C)
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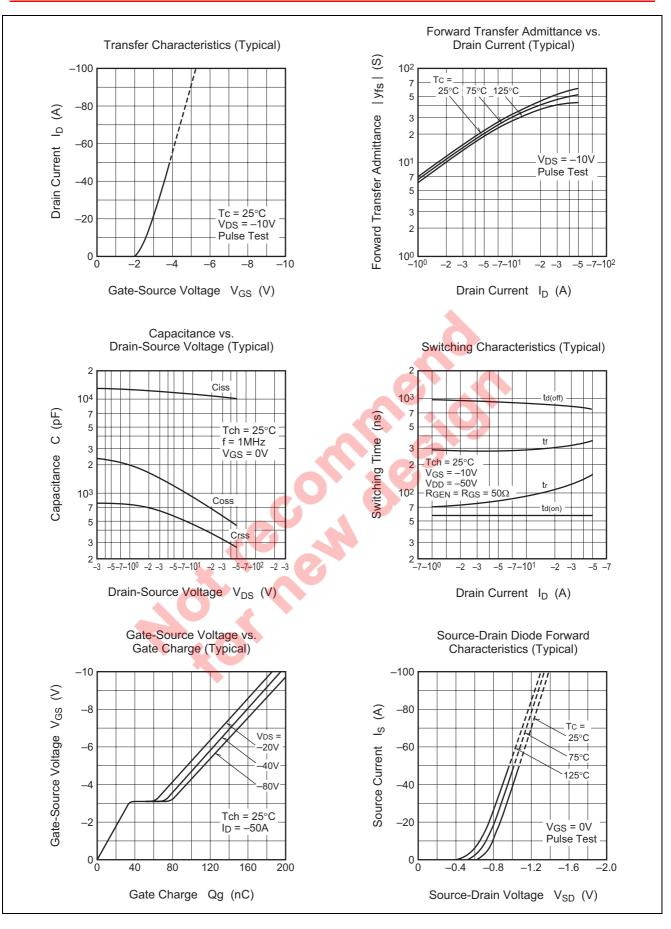
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain-source breakdown voltage	V _{(BR)DSS}	-100	_	—	V	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate-source leakage current	I _{GSS}	_	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$
Drain-source leakage current	I _{DSS}	—	—	-0.1	mA	$V_{DS} = -100 \text{ V}, V_{GS} = 0 \text{ V}$
Gate-source threshold voltage	V _{GS(th)}	-1.3	-1.8	-2.3	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	39	50	mΩ	$I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	47	61	mΩ	$I_D = -25 \text{ A}, V_{GS} = -4 \text{ V}$
Drain-source on-state voltage	V _{DS(ON)}	—	-0.98	-1.25	V	$I_D = -25 \text{ A}, V_{GS} = -10 \text{ V}$
Forward transfer admittance	y _{fs}	—	49.2	—	S	$I_D = -25 \text{ A}, V_{DS} = -10 \text{ V}$
Input capacitance	Ciss	—	11130	—	pF	$V_{DS} = -10 V$, $V_{GS} = 0 V$,
Output capacitance	Coss	—	896	—	pF	f = 1MHz
Reverse transfer capacitance	Crss	—	480	—	pF	
Turn-on delay time	t _{d(on)}	—	57	—	ns	$V_{DD} = -50 \text{ V}, I_D = -25 \text{ A},$
Rise time	tr	—	118	—	ns	$V_{GS} = -10 V$,
Turn-off delay time	t _{d(off)}	—	828	—	ns	$R_{GEN} = R_{GS} = 50 \ \Omega$
Fall time	t _f	—	380	—	ns	
Source-drain voltage	V _{SD}	—	-1.0	-1.5	V	$I_{S} = -25 \text{ A}, V_{GS} = 0 \text{ V}$
Thermal resistance	R _{th(ch-c)}	—	—	3.57	°C/W	Channel to case
Reverse recovery time	t _{rr}	_	100		ns	ls = −50 A, d _{is} /d _t = 100 A/μs



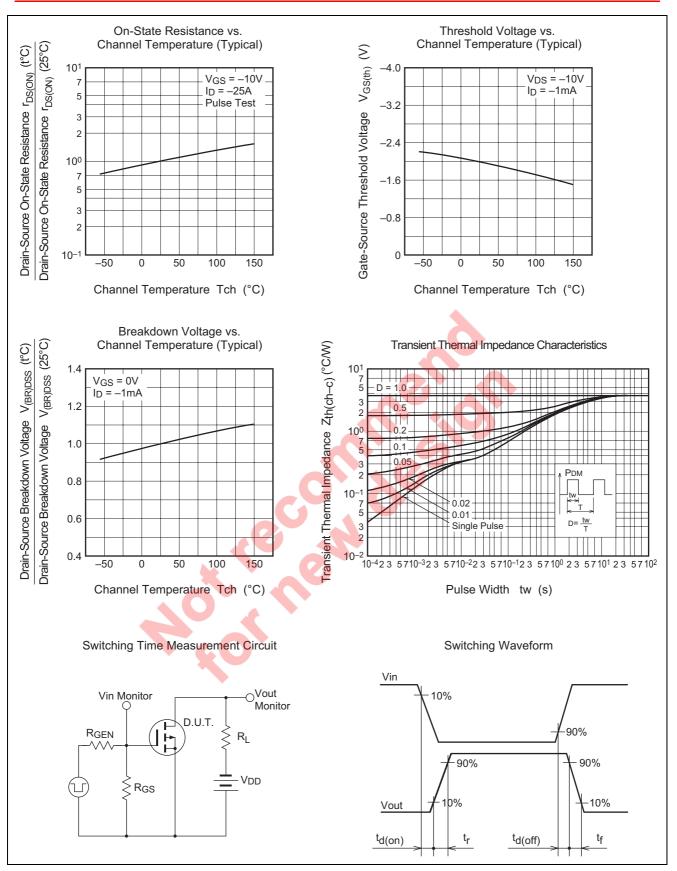
Performance Curves



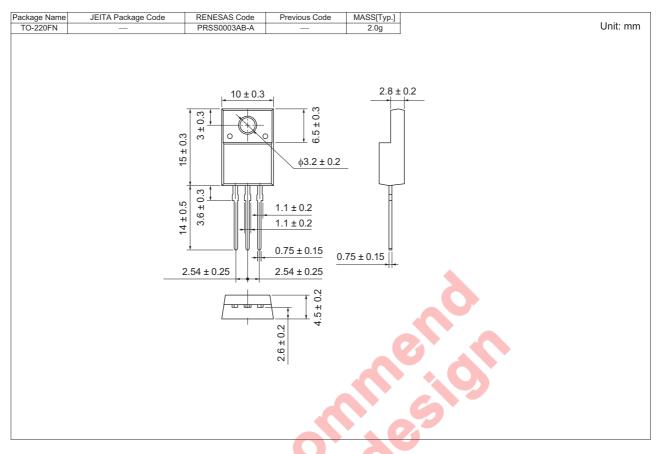








Package Dimensions



Order Code

Lead form	Standard packing	Qu	antity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)		50	Type name	FX50KMJ-2
Lead form	Plastic Magazine (Tube)		50	Type name – Lead forming code	FX50KMJ-2-A8

Note: Please confirm the specification about the shipping in detail.

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